Title:

Graphene and 2D materials: Applications to conventional and emerging devices and circuits.

Abstract:

Graphene material exhibits a number of outstanding electronic and mechanical properties that make them very attractive for micro and nanoelectronic applications. In association with others new 2D materials, it becomes possible to design new devices and circuits architecture.

In this presentation, an overview of recent 2D devices and circuits will be made, with a focus on high frequency applications.

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